

AM26LV31 低压、高速四路差分线路驱动器

1 特性

- 开关频率高达 32MHz
- 由 3.3V 单电源供电运行
- 传播延迟时间 : 8ns (典型值)
- 脉冲偏移时间 : 500ps (典型值)
- 高输出驱动电流 : $\pm 30 \text{ mA}$
- 受控上升和下降时间 : 3ns (典型值)
- 100 Ω 负载时的差分输出电压 : 1.5V (典型值)
- 超低功耗
 - 直流, 0.3mW (最大值)
 - 所有通道 32MHz (空载), 385mW (典型值)
- 支持 5V 逻辑输入及 3.3V 电源
- 针对 AM26C31、AM26LS31 和 MB571 的低压引脚对引脚兼容替换产品
- 在断电情况下具有高输出阻抗
- 驱动器输出短路保护电路
- 封装选项包括小巧 (D, NS) 塑料封装

2 应用

- 电机控制 : 无刷直流和有刷直流
- 现场变送器 : 温度传感器和压力传感器
- 采用 Modbus 的温度传感器或控制器

3 说明

AM26LV31C 和 AM26LV31I 是具有三态输出的 BiCMOS 四路差分线路驱动器。它们与 TIA/EIA-422-B 和 ITU Recommendation V.11 驱动器类似，但电源电压范围较小。

这些器件经过优化，可在高达 32MHz 的开关速率下实现平衡总线传输。输出端可提供非常高的电流，从而驱动双绞线传输线路等平衡线路，并在关断情况下提供高阻抗。四个驱动器均具有使能功能，该功能提供了两种可选输入：有源高电平使能输入和有源低电平使能输入。AM26LV31C 和 AM26LV31I 使用德州仪器 (TI) 专有 LinIMPACT-C60™ 技术进行设计，有助于在不影响速度的情况下实现超低功耗。这些器件会在与 AM26LV32 四路线路接收器配合使用时提供最佳的性能。

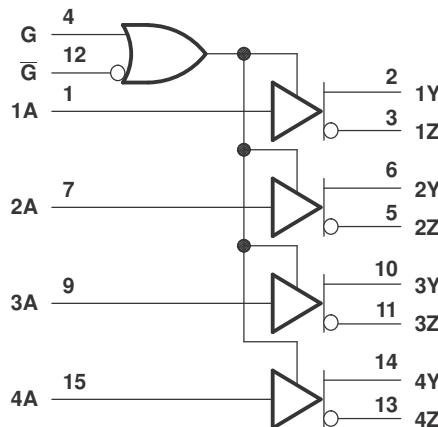
AM26LV31C 的额定工作温度范围为 0°C 至 70°C。AM26LV31I 的额定工作温度范围为 -45°C 至 85°C。

封装信息

器件型号	封装 ⁽¹⁾	封装尺寸 ⁽²⁾
AM26LV31C	SOIC (D) 16	9.9mm x 6mm
AM26LV31I	SOIC (D) 16	9.9mm x 6mm
	SO (NS) 16	10.2mm x 7.8mm

(1) 有关更多信息，请参阅节 11。

(2) 封装尺寸 (长 x 宽) 为标称值，并包括引脚 (如适用)。



逻辑图 (正逻辑)



本资源的原文使用英文撰写。为方便起见，TI 提供了译文；由于翻译过程中可能使用了自动化工具，TI 不保证译文的准确性。为确认准确性，请务必访问 ti.com 参考最新的英文版本 (控制文档)。

Table of Contents

1 特性	1	7.4 Device Functional Modes.....	11
2 应用	1	8 Application and Implementation	12
3 说明	1	8.1 Application Information.....	12
4 Pin Configuration and Functions	3	8.2 Typical Application.....	12
5 Specifications	4	8.3 Power Supply Recommendations.....	13
5.1 Absolute Maximum Ratings.....	4	8.4 Layout.....	13
5.2 ESD Ratings.....	4	9 Device and Documentation Support	15
5.3 Recommended Operating Conditions.....	4	9.1 Device Support.....	15
5.4 Thermal Information.....	4	9.2 接收文档更新通知.....	15
5.5 Electrical Characteristics.....	5	9.3 支持资源.....	15
5.6 Switching Characteristics.....	5	9.4 Trademarks.....	15
5.7 Typical Characteristics.....	6	9.5 静电放电警告.....	15
6 Parameter Measurement Information	7	9.6 术语表.....	15
7 Detailed Description	10	10 Revision History	15
7.1 Overview.....	10	11 Mechanical, Packaging, and Orderable Information	16
7.2 Functional Block Diagram.....	10		
7.3 Feature Description.....	10		

4 Pin Configuration and Functions

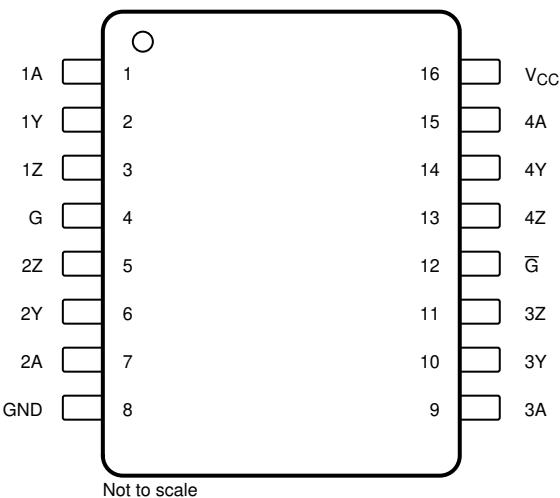


图 4-1. D or NS Package, SOIC 16 Pins
(Top View)

表 4-1. Pin Functions

PIN		I/O	DESCRIPTION
NO.	NAME		
1	1A	I	Driver 1 input
2	1Y	O	Driver 1 output
3	1Z	O	Driver 1 inverted output
4	G	I	Active high enable
5	2Z	O	Driver 2 inverted output
6	2Y	O	Driver 2 output
7	2A	I	Driver 2 input
8	GND	—	Ground pin
9	3A	I	Driver 3 input
10	3Y	O	Driver 3 output
11	3Z	O	Driver 3 inverted output
12	̄G	I	Active low enable
13	4Z	O	Driver 4 inverted output
14	4Y	O	Driver 4 output
15	4A	I	Driver 4 input
16	V _{CC}	—	Power pin

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

	MIN	MAX	UNIT
Supply voltage range, V _{CC} ⁽²⁾	- 0.3	6	V
Input voltage range, V _I	- 0.3	6	V
Output voltage range, V _O	- 0.3	6	V
Storage temperature, T _{stg}	- 65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values are with respect to GND.

5.2 ESD Ratings

		VALUE	UNIT
V _(ESD) Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±3000	V
	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±250	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process..
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

		MIN	NOM	MAX	UNIT
V _{CC}	Supply voltage	3	3.3	3.6	V
V _{IH}	High-level input voltage	2			V
V _{IL}	Low-level input voltage			0.8	V
I _{OH}	High-level output current			- 30	mA
I _{OL}	Low-level output current			30	mA
T _A	AM26LV31C	0	70		°C
	AM26LV31I	- 45	85		°C

5.4 Thermal Information

THERMAL METRIC ⁽¹⁾	D (SOIC)	NS (SO)	UNIT
	16 PINS	16 PINS	
R _{θ JA} Junction-to-ambient thermal resistance	84.6	88.5	°C/W
R _{θ JC(top)} Junction-to-case (top) thermal resistance	43.5	46.2	°C/W
R _{θ JB} Junction-to-board thermal resistance	43.2	50.7	°C/W
ψ _{JT} Junction-to-top characterization parameter	10.4	13.5	°C/W
ψ _{JB} Junction-to-board characterization parameter	42.8	50.3	°C/W
R _{θ JC(bot)} Junction-to-case (bottom) thermal resistance	n/a	n/a	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

5.5 Electrical Characteristics

over recommended operating supply-voltage and free-air temperature ranges (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
V _{IK} Input clamp voltage	I _I = 18mA			- 1.5	V
V _{OH} High-level output voltage	V _{IH} = 2V, I _{OH} = - 12mA	1.85	2.3		V
V _{OL} Low-level output voltage	V _{IL} = 0.8V, I _{OH} = 12mA		0.8	1.05	V
V _{OD} Differential output voltage ⁽²⁾		0.95	1.5		V
V _{OC} Common-mode output voltage	R _L = 100Ω	1.3	1.55	1.9	V
Δ V _{OC} Change in magnitude of common-mode output voltage ⁽²⁾				±0.2	V
I _O Output current with power off	V _O = - 0.25V or 6V, V _{CC} = 0			±100	μA
I _{OZ} Off-state (high-impedance state) output current	V _O = - 0.25V or 6V, G = 0.8V or Ḡ = 2V			±100	μA
I _H High-level input current	V _{CC} = 0 or 3V, V _I = 5.5V			10	μA
I _L Low-level input current	V _{CC} = 3.6V, V _I = 0			- 10	μA
I _{OS} Short-circuit output current	V _{CC} = 3.6V, V _O = 0			- 200	mA
I _{CC} Supply current (all drivers)	V _I = V _{CC} or GND, No load			100	μA
C _{PD} Power-dissipation capacitance (all drivers) ⁽³⁾	No load		160		pF

(1) All typical values are at V_{CC} = 3.3V, T_A = 25°C.

(2) Δ|V_{OD}| and Δ|V_{OC}| are the changes in magnitude of V_{OD} and V_{OC}, respectively, that occur when the input is changed from a high level to a low level.

(3) C_{PD} determines the no-load dynamic current consumption. I_S = C_{PD} × V_{CC} × f + I_{CC}

5.6 Switching Characteristics

PARAMETER	TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
t _{PLH} Propagation delay time, low- to high-level output	See 图 6-2	4	8	20	ns
t _{PHL} Propagation delay time, high- to low-level output		4	8	20	ns
t _f Transition time (t _r or t _f)			3		ns
SR Slew rate, single-ended output voltage	See Note (2) and 图 6-2		0.3	1	V/ns
t _{PZH} Output-enable time to high level	See 图 6-3		10	20	ns
t _{PZL} Output-enable time to low level	See 图 6-4		10	20	ns
t _{PHZ} Output-disable time from high level	See 图 6-3		10	20	ns
t _{PLZ} Output-disable time from low level	See 图 6-4		10	20	ns
t _{sk(p)} Pulse skew	f = 32MHz, See Note (3)		0.5	3	ns
t _{sk(o)} Skew limit	f = 32MHz			3	ns
t _{sk(lim)} Skew limit (device to device)	f = 32 MHz, See Note (4)			3	ns

(1) All typical values are at V_{CC} = 3.3V, T_A = 25°C.

(2) Slew rate is defined by 方程式 1

(3) Pulse skew is defined as the |t_{PLH} - t_{PHL}| of each channel of the same device.

(4) Skew limit (device to device) is the maximum difference in propagation delay times between any two channels of any two devices.

$$SR = \frac{90\% (V_{OH} - V_{OL}) - 10\% (V_{OH} - V_{OL})}{t_f}, \text{ the differential slew rate of } V_{CC} \text{ is } 2 \times SR. \quad (1)$$

5.7 Typical Characteristics

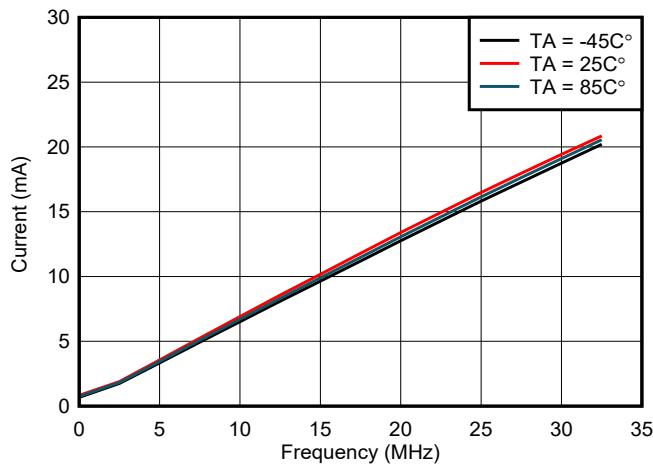


图 5-1. Current vs Frequency

6 Parameter Measurement Information

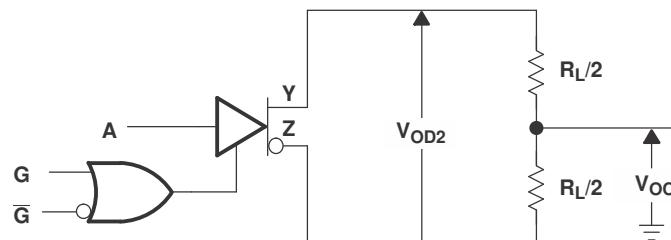
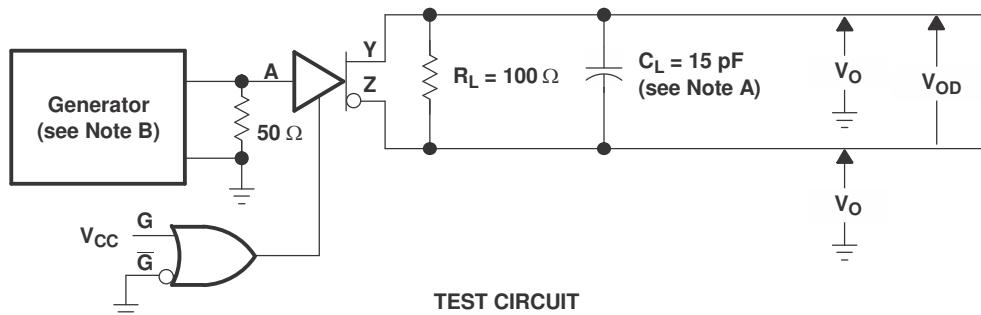
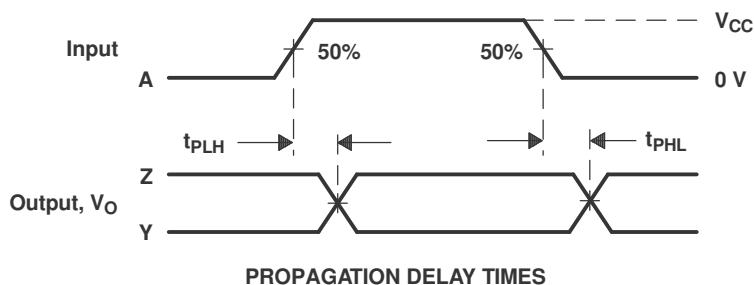


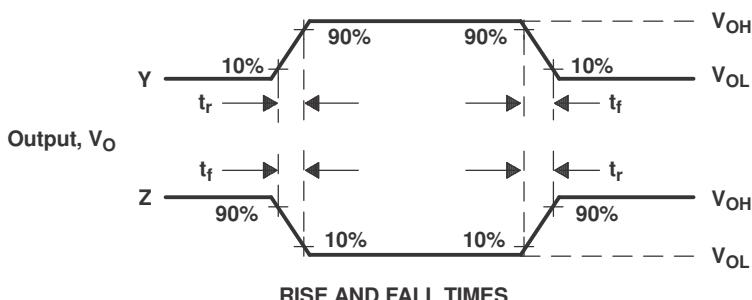
图 6-1. Differential and Common-Mode Output Voltages



TEST CIRCUIT



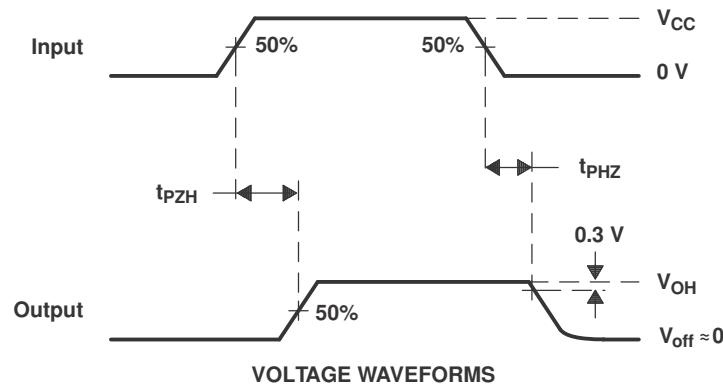
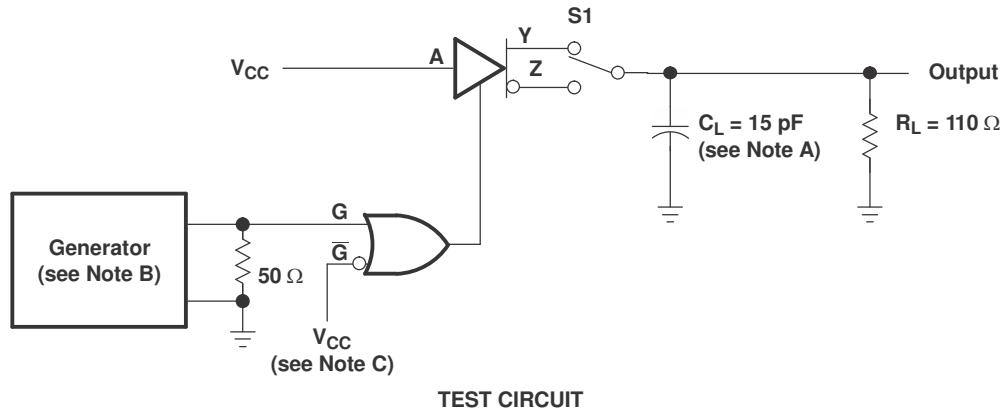
PROPAGATION DELAY TIMES



RISE AND FALL TIMES

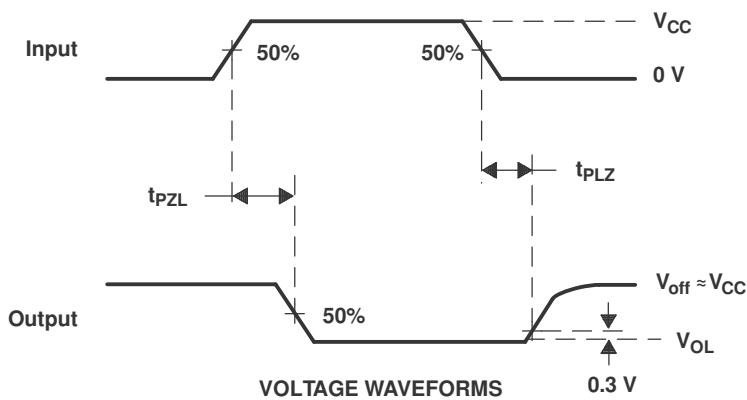
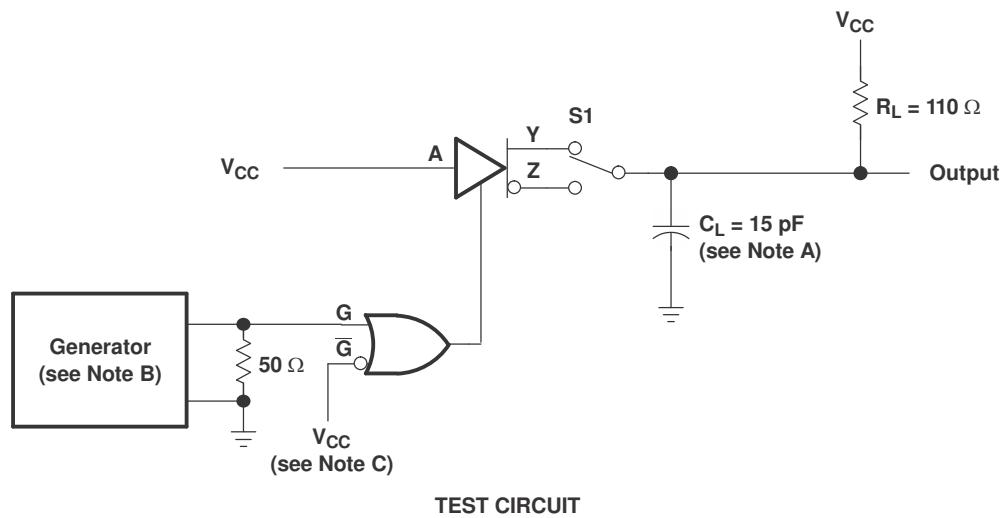
- A. C_L includes probe and jig capacitance.
- B. The input pulse is supplied by a generator having the following characteristics: PRR = 10MHz, $Z_0 = 50 \Omega$, 50%v duty cycle, t_r and $t_f \leq 10\text{ns}$.

图 6-2. Test Circuit and Voltage Waveforms, t_{PHL} and t_{PLH}



- C_L includes probe and jig capacitance.
- The input pulse is supplied by a generator having the following characteristics: PRR = 1MHz, $Z_O = 50 \Omega$, 50%v duty cycle, t_r and t_f (10% to 90%) $\leq 2\text{ns}$.
- To test the active-low enable \bar{G} , ground G and apply an inverted waveform to \bar{G} .

图 6-3. Test Circuit and Voltage Waveforms, t_{PZH} and t_{PHZ}



- A. C_L includes probe and jig capacitance.
- B. The input pulse is supplied by a generator having the following characteristics: PRR = 1MHz, $Z_O = 50 \Omega$, 50%v duty cycle, t_r and t_f (10% to 90%) $\leq 2\text{ns}$.
- C. To test the active-low enable \bar{G} , ground G and apply an inverted waveform to \bar{G} .

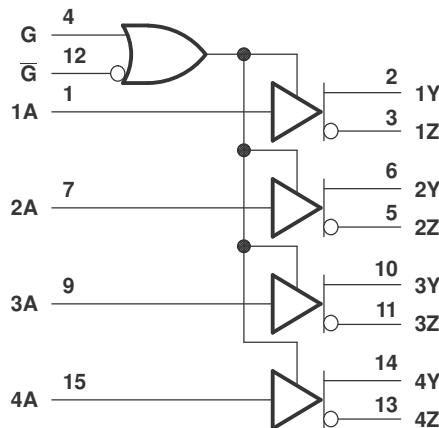
图 6-4. Test Circuit and Voltage Waveforms, t_{PZL} and t_{PLZ}

7 Detailed Description

7.1 Overview

The AM26LV31C and AM26LV31I are BiCMOS quadruple differential line drivers with 3-state outputs. The devices are designed to be similar to TIA/EIA-422-B and ITU Recommendation V.11 drivers with a single 3.3-V power supply. The drivers also integrate active-high and active-low enables for precise device control.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Active high and active low

The devices can be configured using the G and G logic inputs to select transmitter output. A logic high on the G pin or a logic low on the G pin enables the device to operate. These pins are simply a way to configure the logic to match that of the receiving or transmitting controller or microprocessor.

7.3.2 Operates from a 3.3-V Supply with up to 5-V Logic

While the transmitters operate from a single 3.3-V rail, the logic can operate off the same rail or another 5-V rail, making designs much more flexible to communicate to controllers.

7.3.3 High Speed Transmission

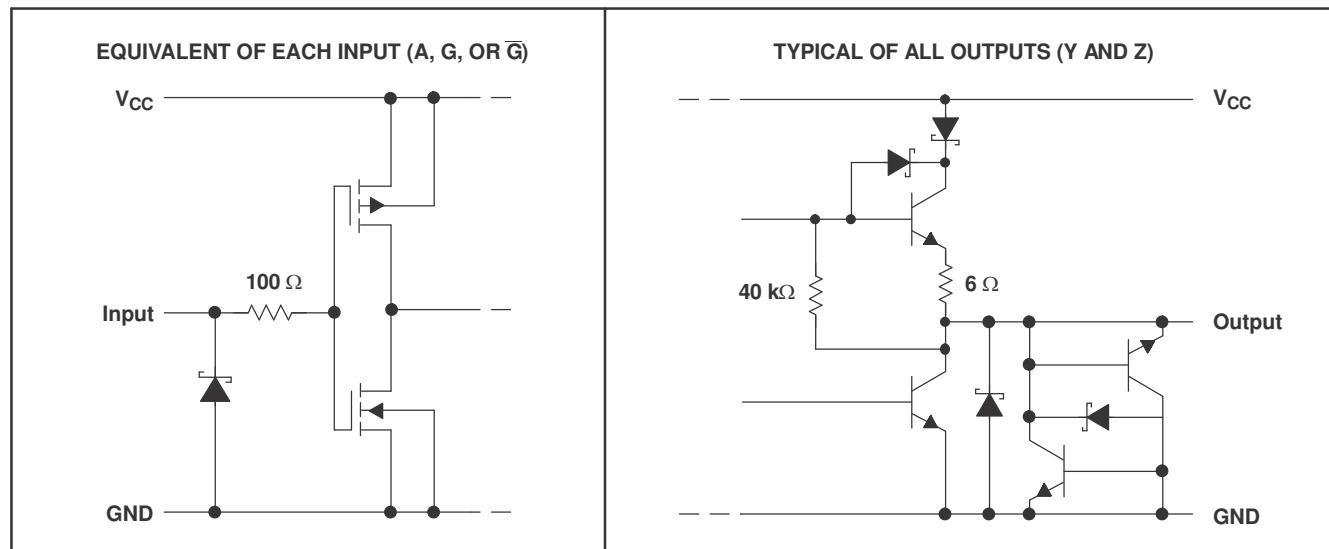
The AM26LV31C and AM26LV31I are optimized for balanced-bus transmission at switching rates up to 32 MHz. The devices are designed using Texas Instruments proprietary LinIMPACT-C60™ technology, facilitating ultra-low power consumption without sacrificing speed.

7.4 Device Functional Modes

表 7-1. Function Table⁽¹⁾

INPUT A	ENABLES		OUTPUTS	
	G	\bar{G}	Y	Z
H	H	X	H	L
L	H	X	L	H
H	X	L	H	L
L	X	L	L	H
X	L	H	Z	Z

(1) H = high level, L = low level, X = irrelevant, Z = high impedance (off)



All resistor values are nominal.

图 7-1. Schematic (Each Driver)

8 Application and Implementation

备注

以下应用部分中的信息不属TI 器件规格的范围，TI 不担保其准确性和完整性。TI 的客户应负责确定器件是否适用于其应用。客户应验证并测试其设计，以确保系统功能。

8.1 Application Information

When designing a system that uses drivers, receivers, and transceivers, proper cable termination is essential for highly reliable applications with reduced reflections in the transmission line. If termination is used, it can be placed at the end of the cable near the last receiver. Factors to consider when determining the type of termination usually are performance requirements of the application and the ever-present factor, cost. The different types of termination techniques discussed are unterminated lines, parallel termination, AC termination, and multipoint termination. For laboratory experiments, 100 feet of 100- Ω , 24-AWG, twisted-pair cable (Bertek) was used. A single driver and receiver, TI AM26LV31C and AM26LV32C, respectively, were tested at room temperature with a 3.3-V supply voltage. The first plot shows output waveforms from the driver at the start of the cable (A/B); the second plot shows input waveforms to the receiver at the far end of the cable (Y).

8.2 Typical Application

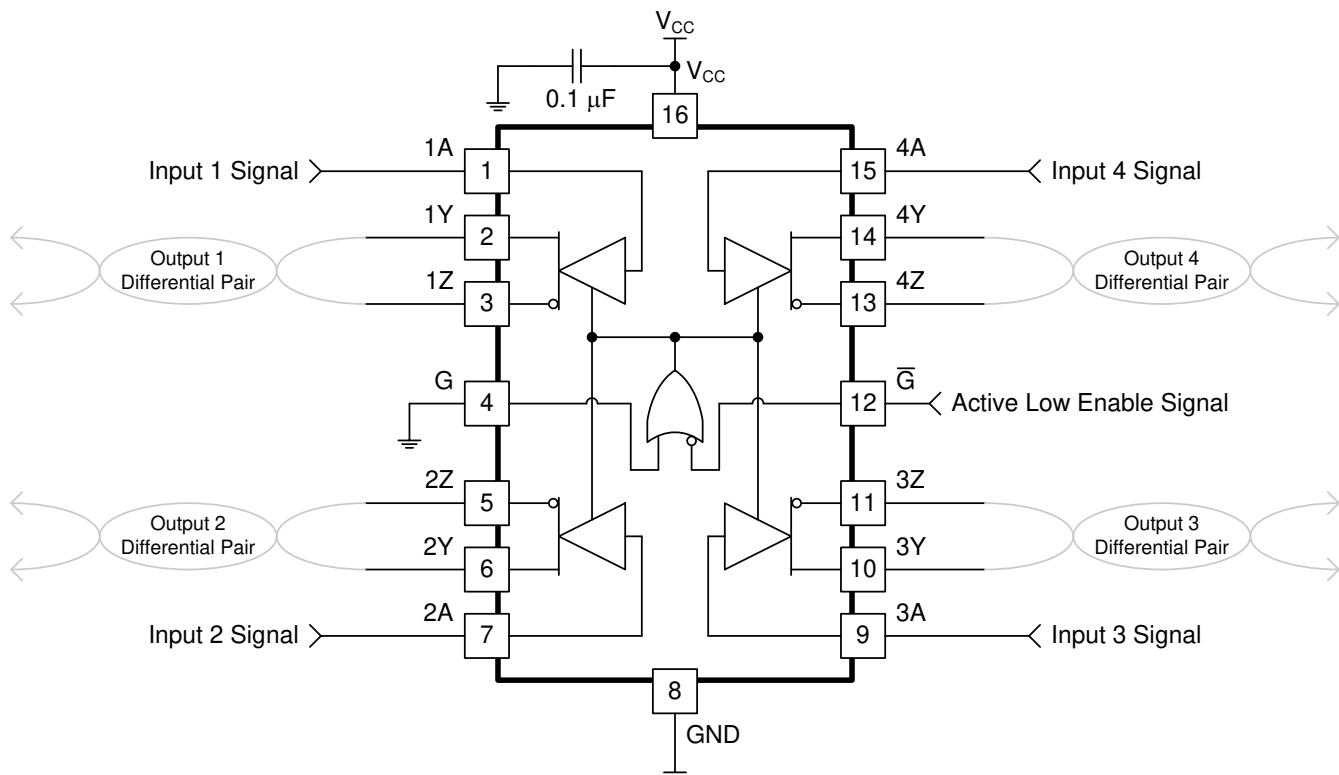


图 8-1. Differential Terminated Configuration With All Channels and Active Low Enable Used

8.2.1 Design Requirements

Resistor and capacitor (if used) termination values are shown for each laboratory experiment, but vary from system to system. For example, the termination resistor, R_T , must be within 20% of the characteristic impedance, Z_0 , of the cable and can vary from about 80Ω to 120Ω .

This example requires the following:

- 3.3-V power source
- RS-485 bus operating at 32 MHz or less
- Connector that ensures the correct polarity for port pins

8.2.2 Detailed Design Procedure

Ensure values in Absolute Maximum Ratings are not exceeded. Supply voltage, V_{IH} , and V_{IL} must comply with Recommended Operating Conditions.

Place the device close to bus connector to keep traces (stub) short to prevent adding reflections to the bus line. If desired, add external fail-safe biasing to ensure 200 mV on the A-B port, if the drive is in high impedance state (see Failsafe in RS-485 data buses).

8.2.3 Application Curves

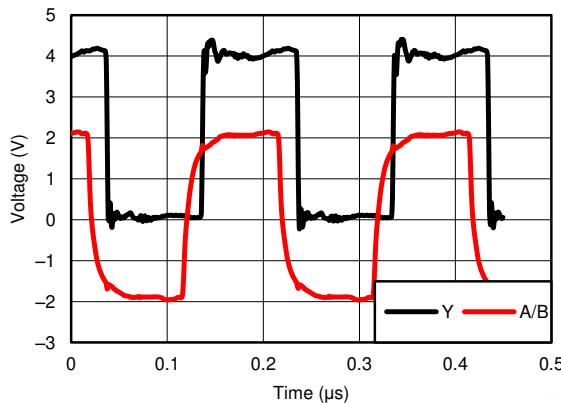


图 8-2. Differential 120- Ω Terminated Output Waveforms (Cat 5E Cable)

8.3 Power Supply Recommendations

Place a $0.1\text{-}\mu\text{F}$ bypass capacitors close to the power-supply pins to reduce errors coupling in from noisy or high impedance power supplies.

8.4 Layout

8.4.1 Layout Guidelines

For best operational performance of the device, use good PCB layout practices, including:

- Noise can propagate into analog circuitry through the power pins of the circuit as a whole, as well as the operational amplifier. Bypass capacitors are used to reduce the coupled noise by providing low impedance power sources local to the analog circuitry. Connect low-ESR, $0.1\text{-}\mu\text{F}$ ceramic bypass capacitors between supply pin and ground, placed as close to the device as possible.
- Separate grounding for analog and digital portions of circuitry is one of the simplest and most effective methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground planes. A ground plane helps distribute heat and reduces EMI noise pickup. Make sure to physically separate digital and analog grounds, paying attention to the flow of the ground current.

- To reduce parasitic coupling, run the input traces as far away from the supply or output traces as possible. If it is not possible to keep them separate, it is much better to cross the sensitive trace perpendicular as opposed to in parallel with the noisy trace.
- Keep the length of input traces as short as possible. Always remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.

8.4.2 Layout Example

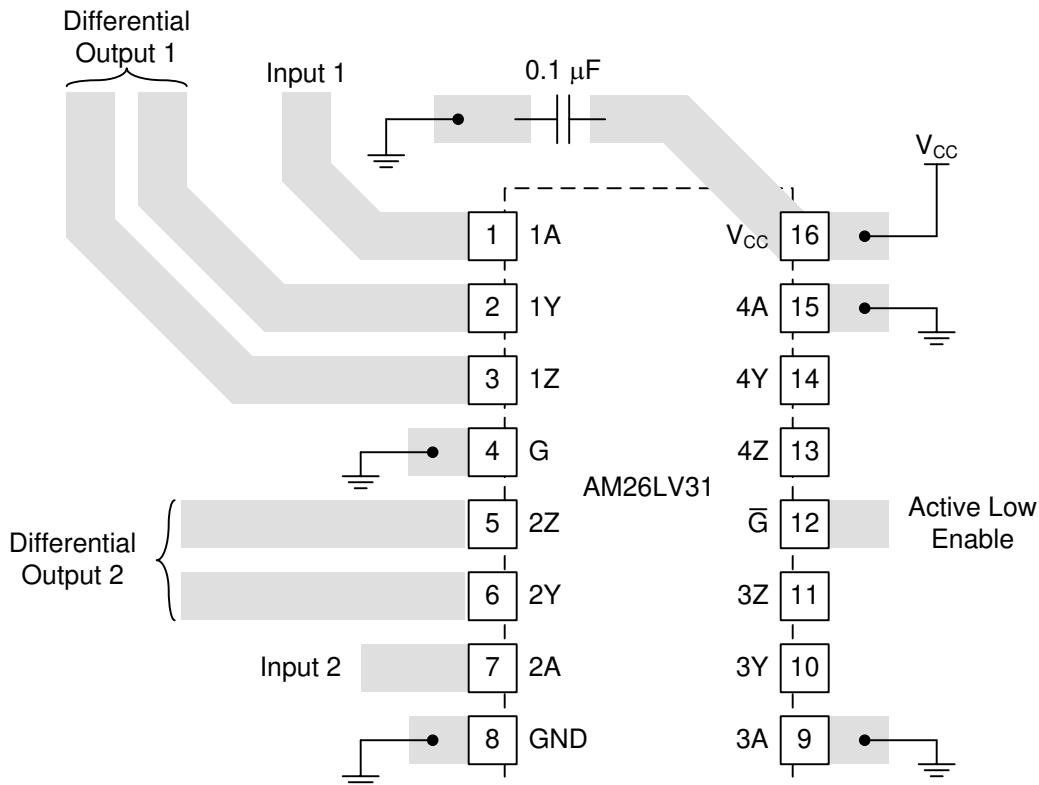


图 8-3. Trace Layout on PCB and Recommendations

9 Device and Documentation Support

9.1 Device Support

9.1.1 Development Support

9.2 接收文档更新通知

要接收文档更新通知，请导航至 [ti.com](#) 上的器件产品文件夹。点击 [订阅更新](#) 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

9.3 支持资源

[TI E2E™ 支持论坛](#) 是工程师的重要参考资料，可直接从专家获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题可获得所需的快速设计帮助。

链接的内容由各个贡献者“按原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的《[使用条款](#)》。

9.4 Trademarks

LinIMPACT-C60™ is a trademark of Texas Instruments.

TI E2E™ is a trademark of Texas Instruments.

所有商标均为其各自所有者的财产。

9.5 静电放电警告



静电放电 (ESD) 会损坏这个集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理和安装程序，可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

9.6 术语表

[TI 术语表](#) 本术语表列出并解释了术语、首字母缩略词和定义。

10 Revision History

注：以前版本的页码可能与当前版本的页码不同

Changes from Revision H (April 2018) to Revision I (April 2024)	Page
• 将“器件信息”更改为封装信息表.....	1
• Changed the <i>Thermal Information</i> table values.....	4
• Changed 图 5-1	6
• Changed the Note B in 图 6-2	7

Changes from Revision G (May 2005) to Revision H (April 2018)	Page
• 添加了器件信息表、ESD 等级表、特性说明部分、器件功能模式、应用和实施部分、电源相关建议部分、布局部分、器件和文档支持部分以及机械、封装和可订购信息部分.....	1
• Changed the t_{PLH} and t_{PHL} MAX value From: 12 ns To: 20 ns in the <i>Switching Characteristics</i>	5
• Changed the $t_{sk(p)}$ and $t_{sk(o)}$ MAX value From: 1.5 ns To: 3 ns in the <i>Switching Characteristics</i>	5

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
AM26LV31CD	Obsolete	Production	SOIC (D) 16	-	-	Call TI	Call TI	0 to 70	AM26LV31C
AM26LV31CDR	Obsolete	Production	SOIC (D) 16	-	-	Call TI	Call TI	0 to 70	AM26LV31C
AM26LV31CDRG4	Obsolete	Production	SOIC (D) 16	-	-	Call TI	Call TI	0 to 70	AM26LV31C
AM26LV31CNSR	Obsolete	Production	SOP (NS) 16	-	-	Call TI	Call TI	0 to 70	26LV31
AM26LV31ID	Obsolete	Production	SOIC (D) 16	-	-	Call TI	Call TI	-45 to 85	AM26LV31I
AM26LV31IDR	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-45 to 85	AM26LV31I
AM26LV31IDR.A	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-45 to 85	AM26LV31I
AM26LV31INSR	Active	Production	SOP (NS) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-45 to 85	26LV31I
AM26LV31INSR.A	Active	Production	SOP (NS) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-45 to 85	26LV31I

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

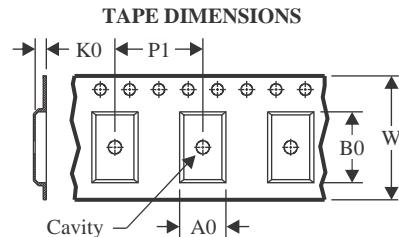
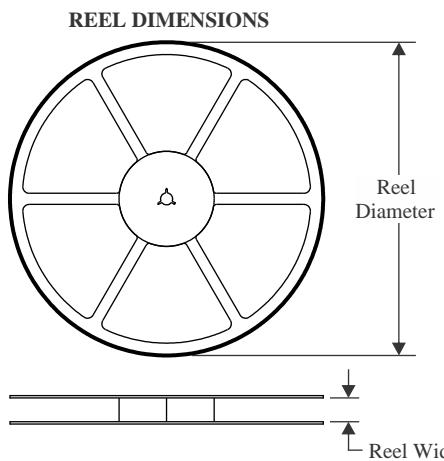
⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

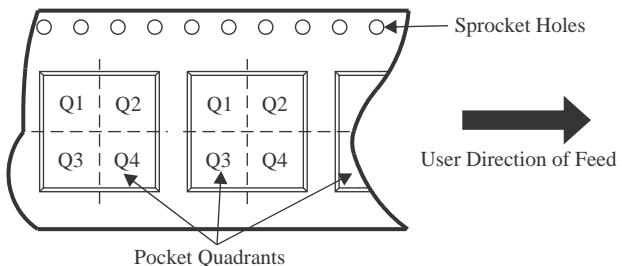
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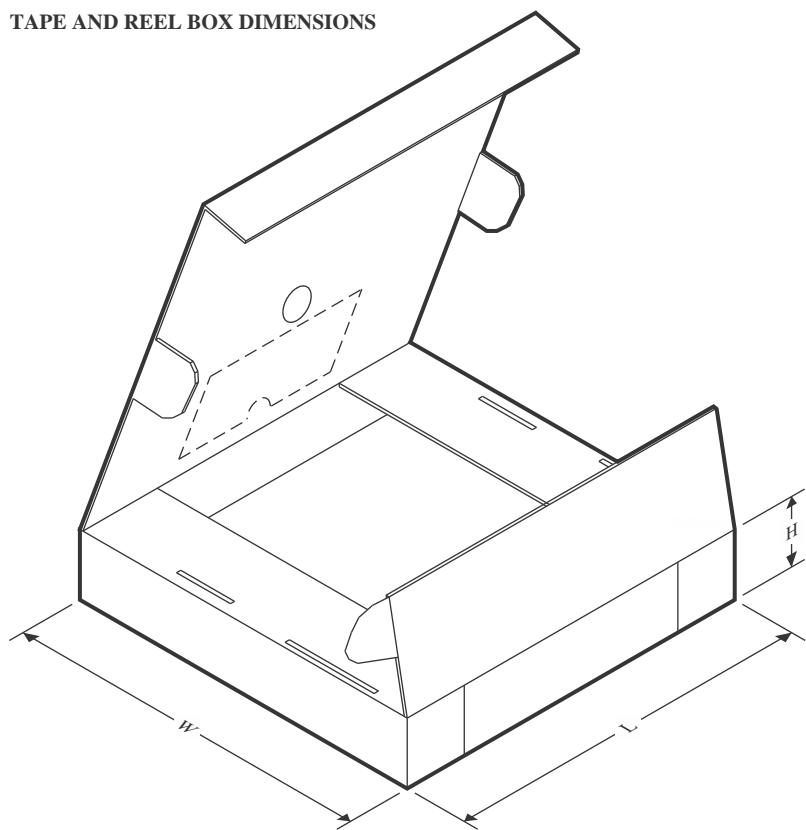
TAPE AND REEL INFORMATION

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
AM26LV31IDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
AM26LV31IDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
AM26LV31INSR	SOP	NS	16	2000	330.0	16.4	8.1	10.4	2.5	12.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
AM26LV31IDR	SOIC	D	16	2500	340.5	336.1	32.0
AM26LV31IDR	SOIC	D	16	2500	353.0	353.0	32.0
AM26LV31INSR	SOP	NS	16	2000	353.0	353.0	32.0

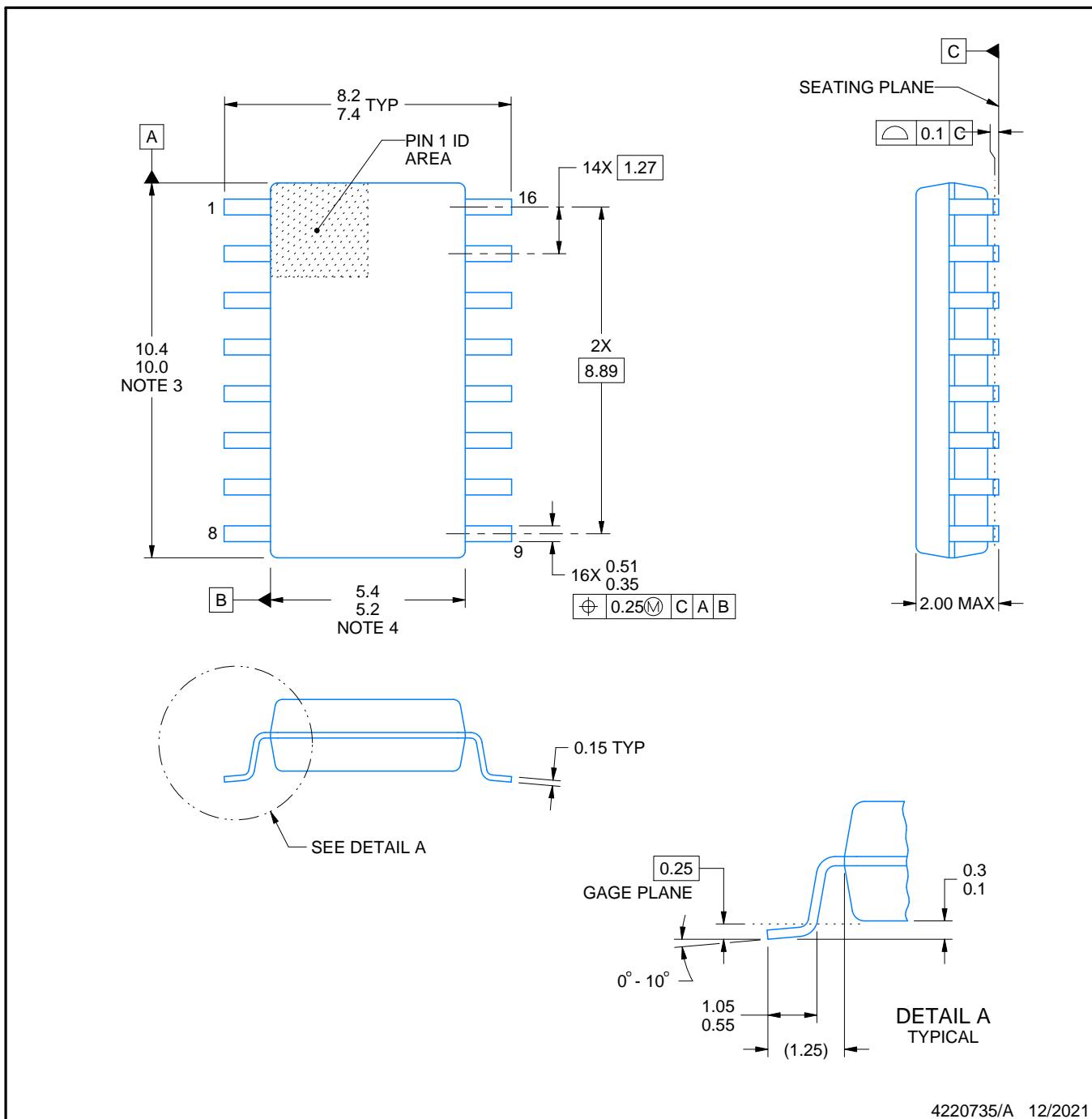
NS0016A



PACKAGE OUTLINE

SOP - 2.00 mm max height

SOP



4220735/A 12/2021

NOTES:

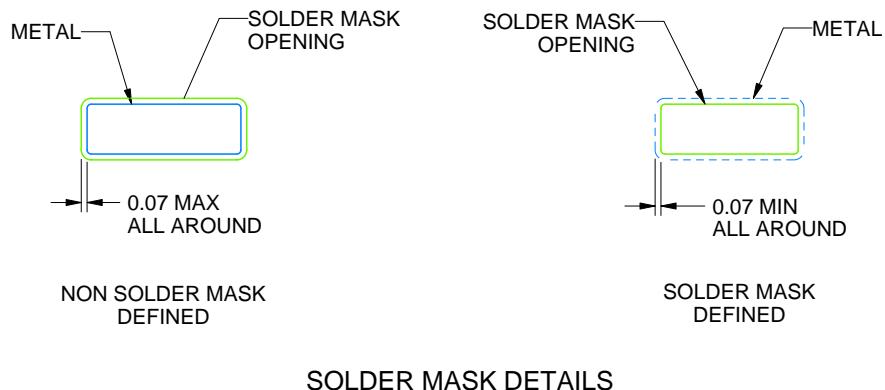
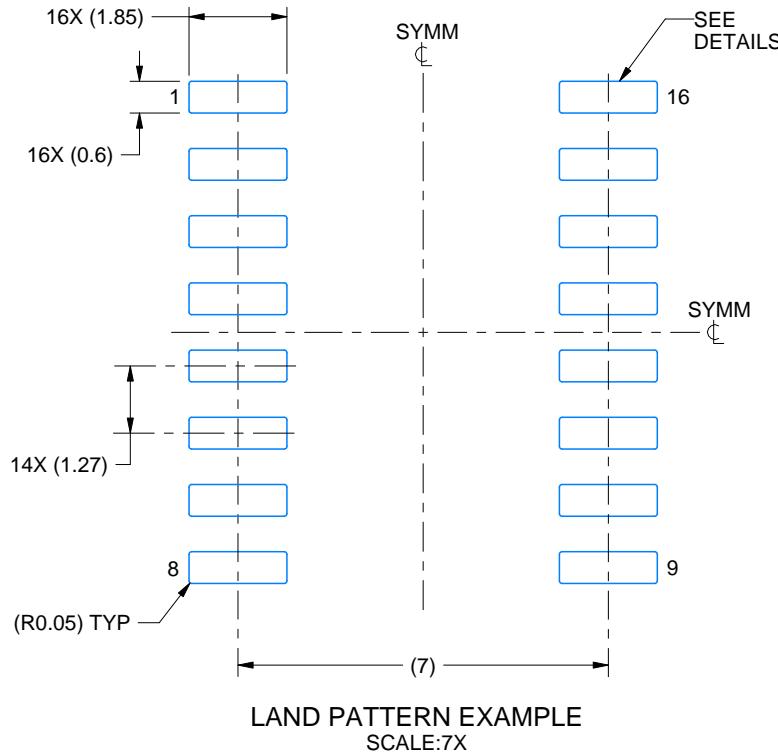
- All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- This drawing is subject to change without notice.
- This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
- This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.

EXAMPLE BOARD LAYOUT

NS0016A

SOP - 2.00 mm max height

SOP



4220735/A 12/2021

NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

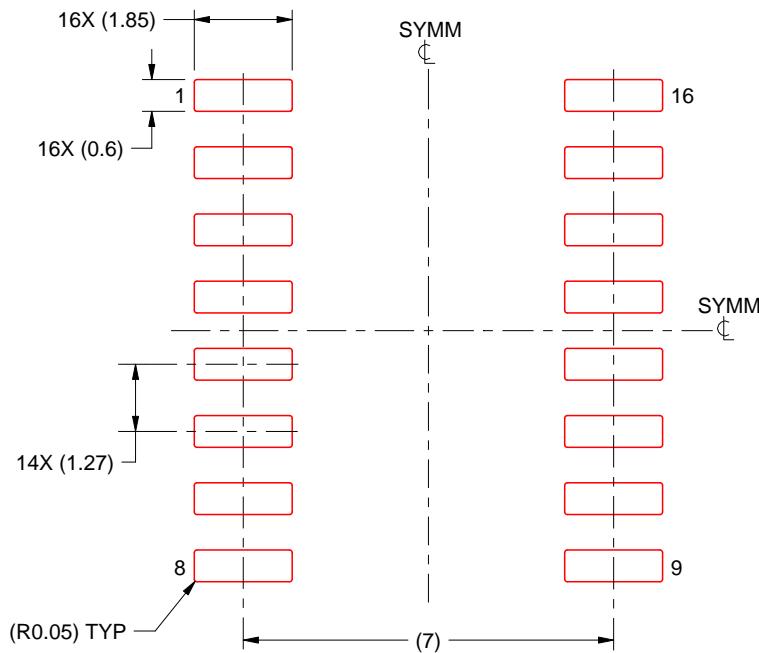
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

NS0016A

SOP - 2.00 mm max height

SOP



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:7X

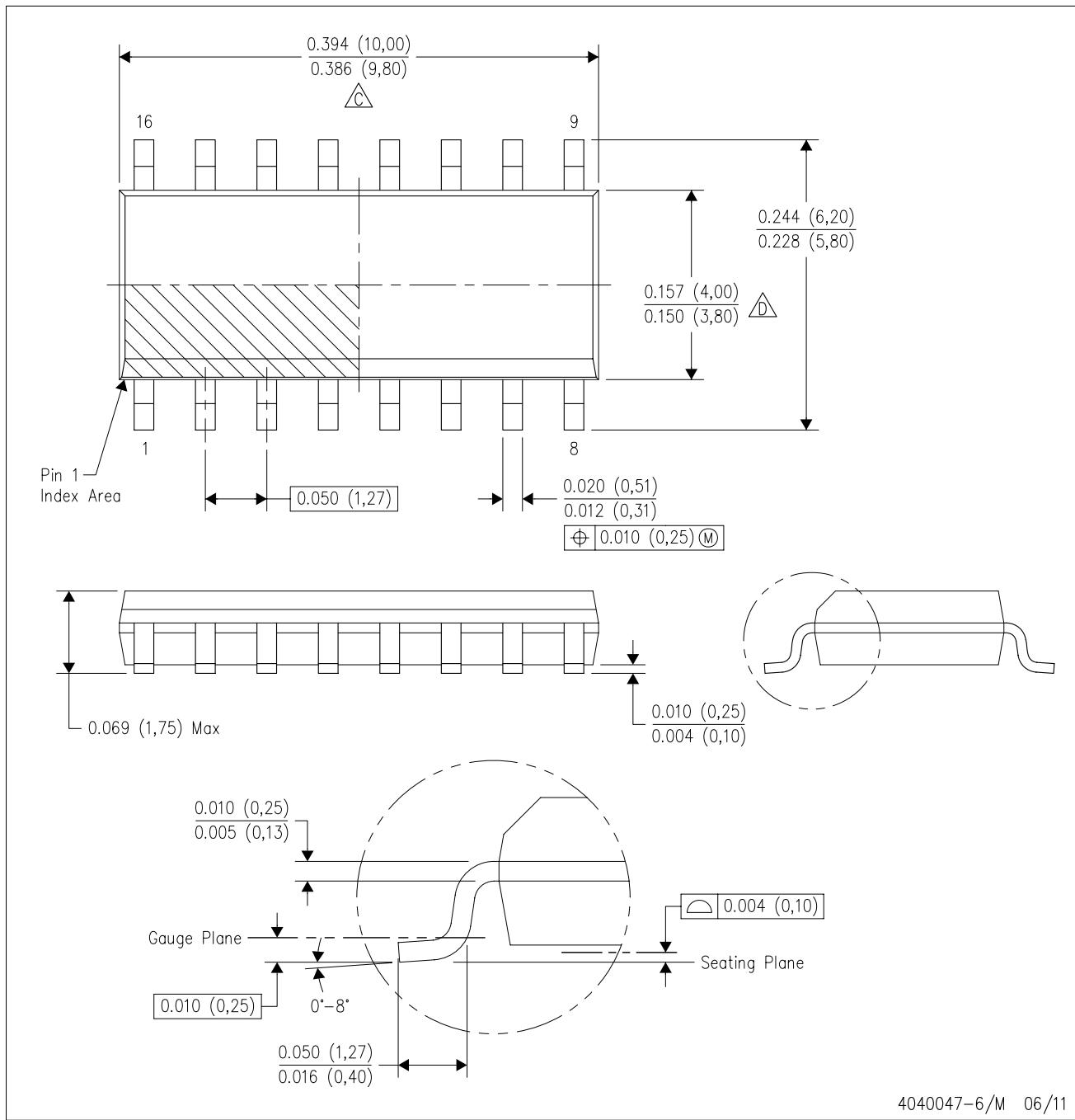
4220735/A 12/2021

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.

D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.

E. Reference JEDEC MS-012 variation AC.

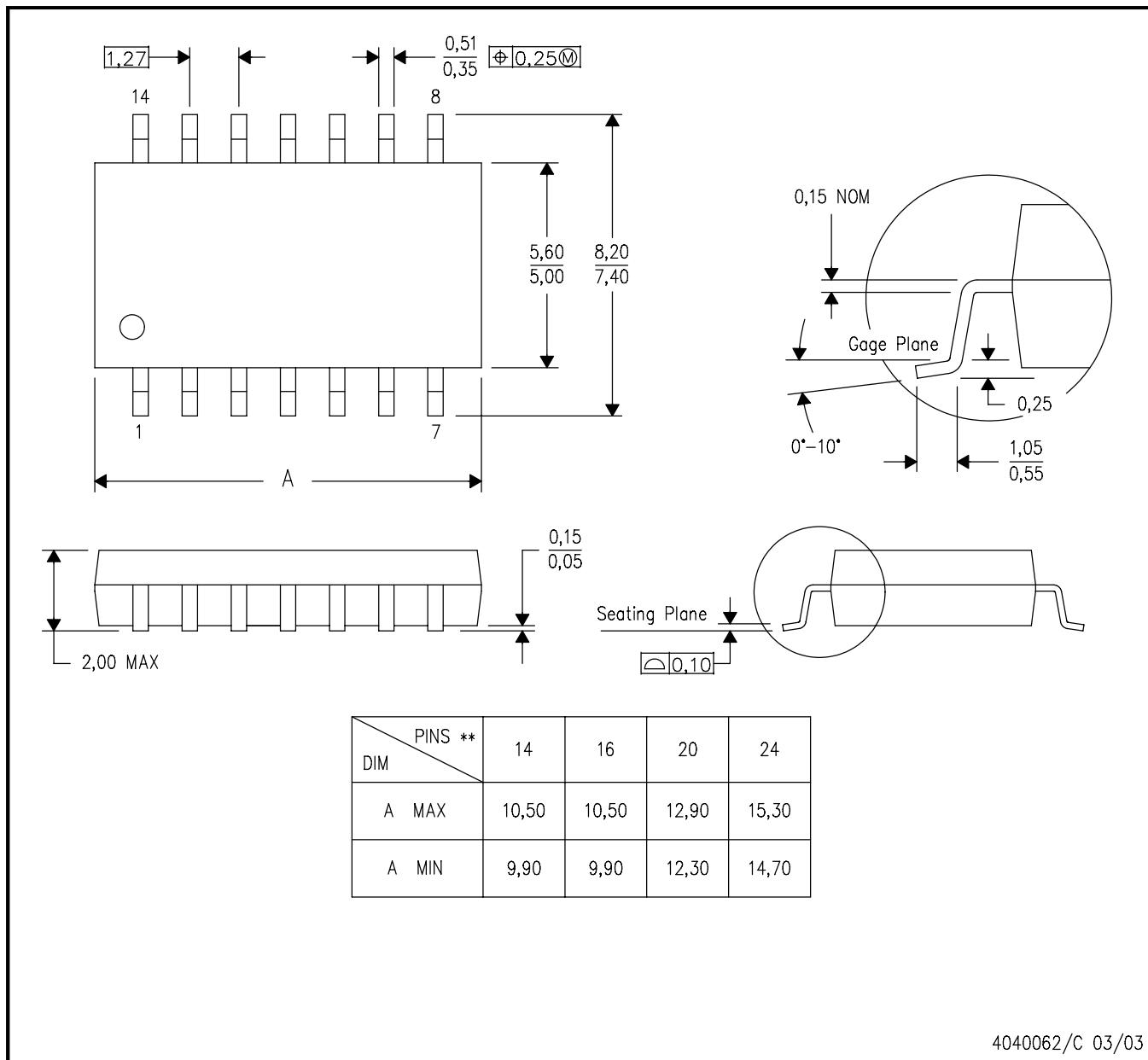
4040047-6/M 06/11

MECHANICAL DATA

NS (R-PDSO-G)**

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES: A. All linear dimensions are in millimeters.
 B. This drawing is subject to change without notice.
 C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

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